NSN 5962-01-090-0166

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-090-0166 **Body Length:** Between 0.735 inches and 0.830 inches **Body Width:** Between 0.270 inches and 0.291 inches **Body Height:** Between 0.140 inches and 0.180 inches **Operating Tempurature Range:** -65.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and high speed and w/enable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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